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(54) **METHOD AND SYSTEM FOR COMMUNICATING VIA LEAKY WAVE ANTENNAS WITHIN A FLIP-CHIP BONDED STRUCTURE**

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(57) **ABSTRACT**

Methods and systems for communicating via leaky wave antennas (LWAs) within a flip-chip bonded structure are disclosed and may include communicating RF signals in a wireless device including one or more LWAs between a plurality of support structures, the structures being coupled via flip-chip bonding. Low-frequency signals may be communicated via flip-chip bonding contacts. The RF signals may be communicated perpendicular to a surface and/or at a desired angle from the surface of the structures, which may include at least one of: an integrated circuit, an integrated circuit package, and a printed circuit board. The LWAs may include microstrip and/or coplanar waveguides where a cavity height of the LWAs may be configured by controlling spacing between conductive lines in the waveguides. The low-frequency signals may include DC bias voltages. The RF signals may be communicated from a single LWA to a plurality of LWAs.

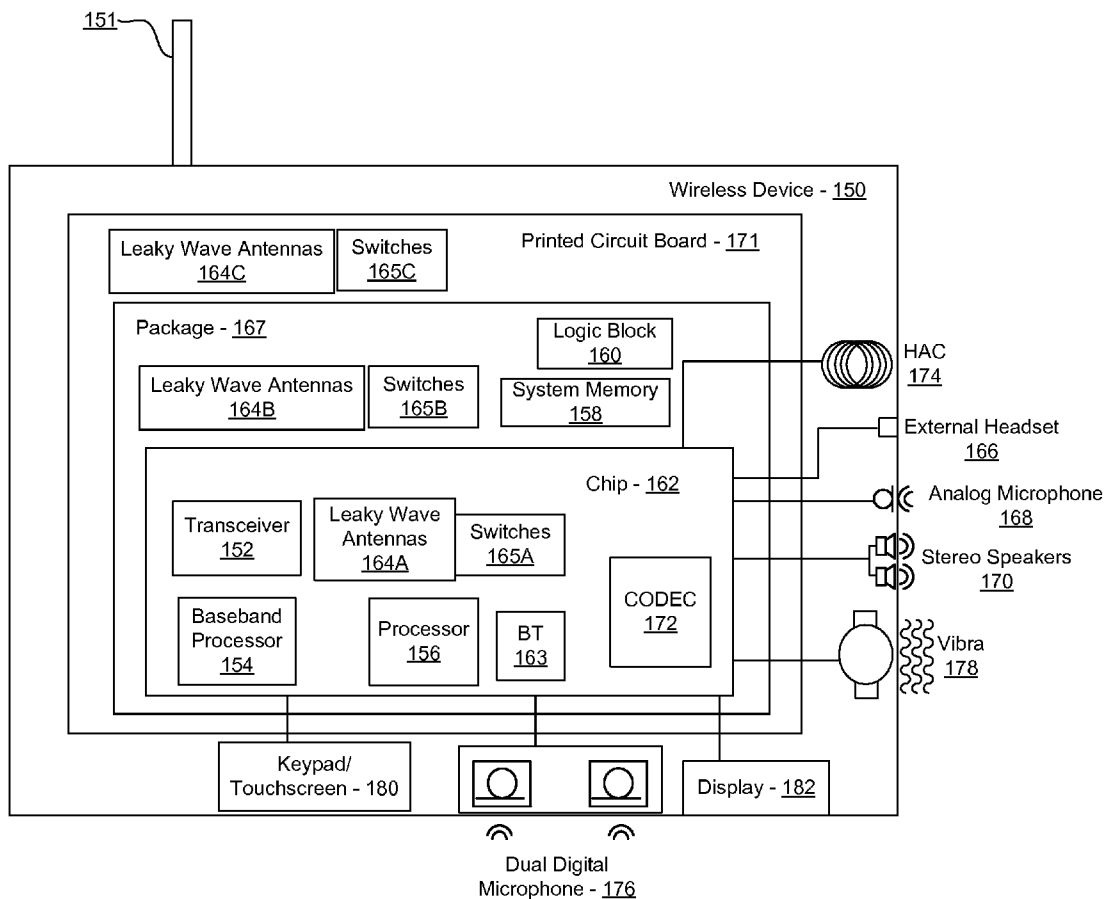
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**Related U.S. Application Data**

(60) Provisional application No. 61/246,618, filed on Sep. 29, 2009, provisional application No. 61/185,245, filed on Jun. 9, 2009.



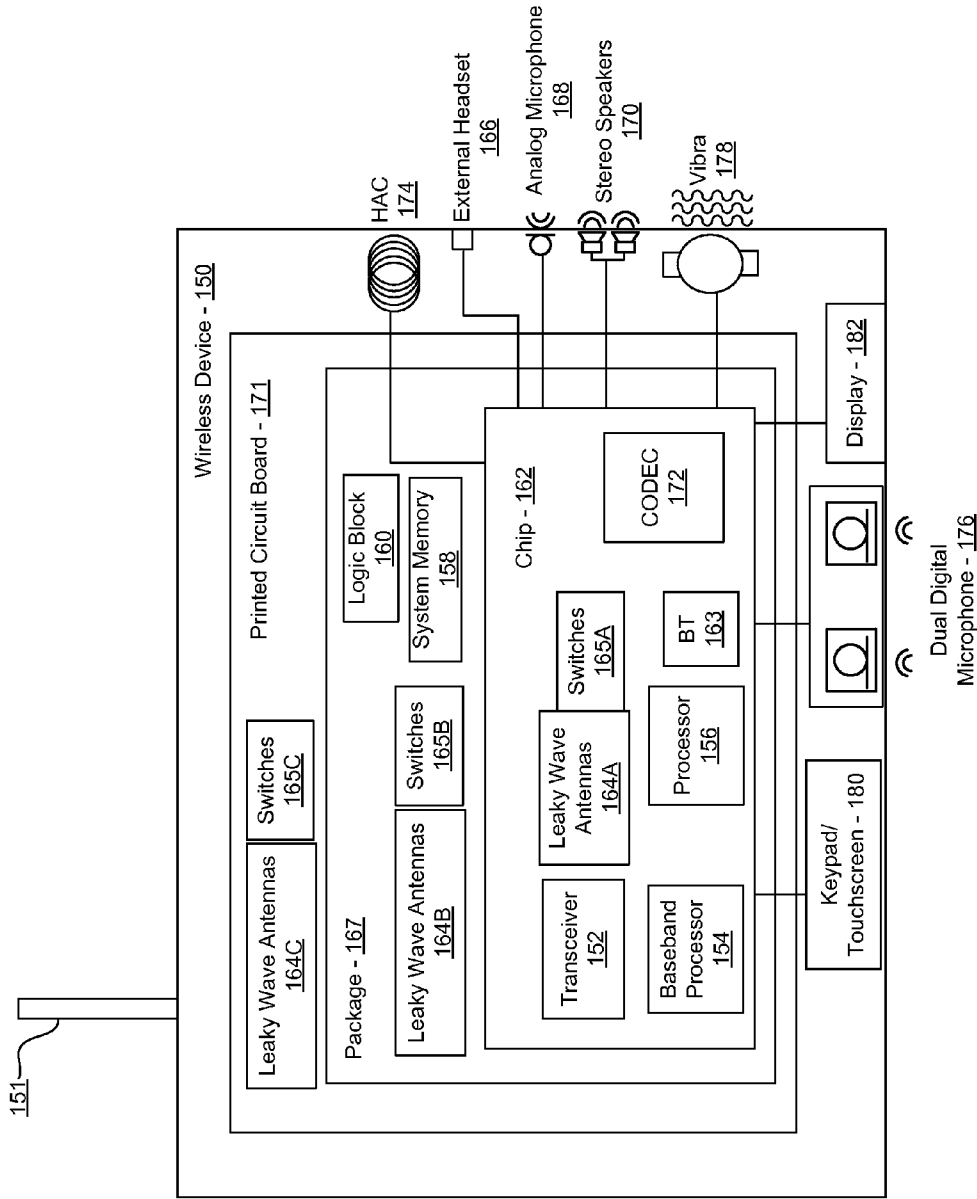


FIG. 1

164A-164C

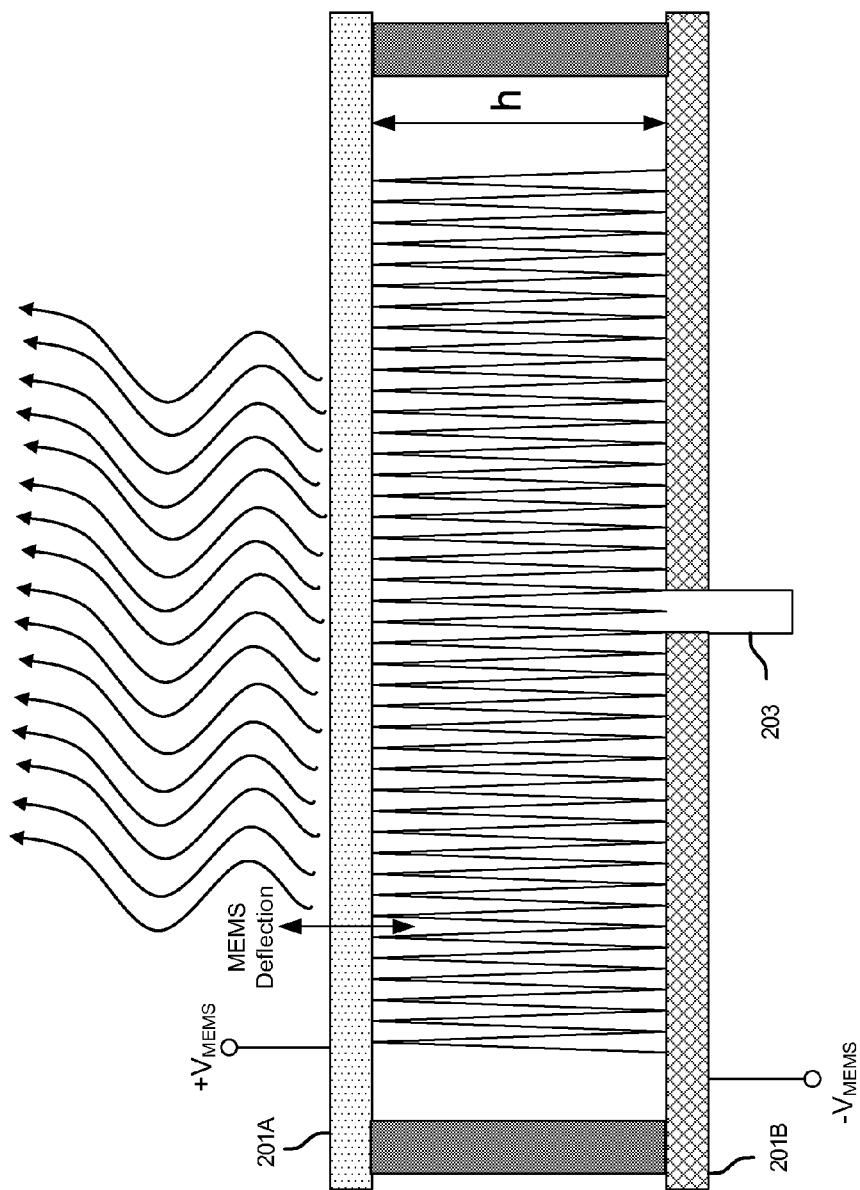


FIG. 2

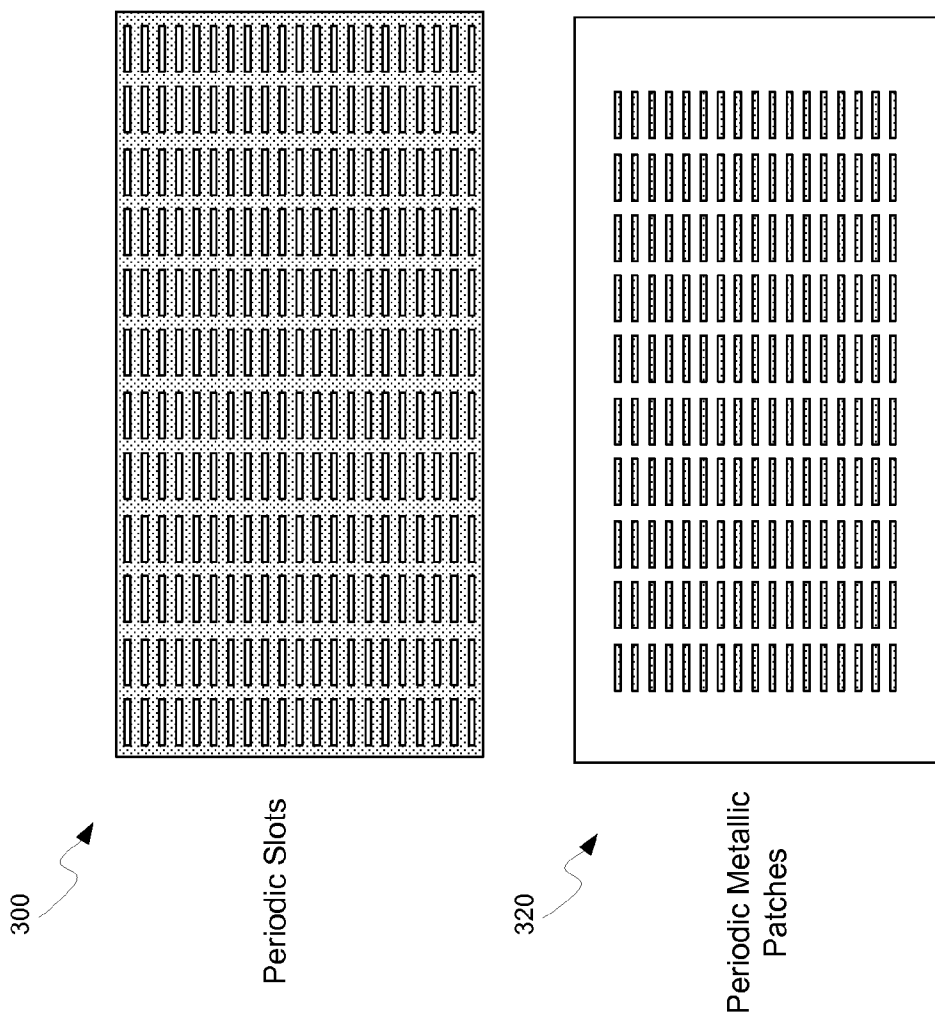


FIG. 3

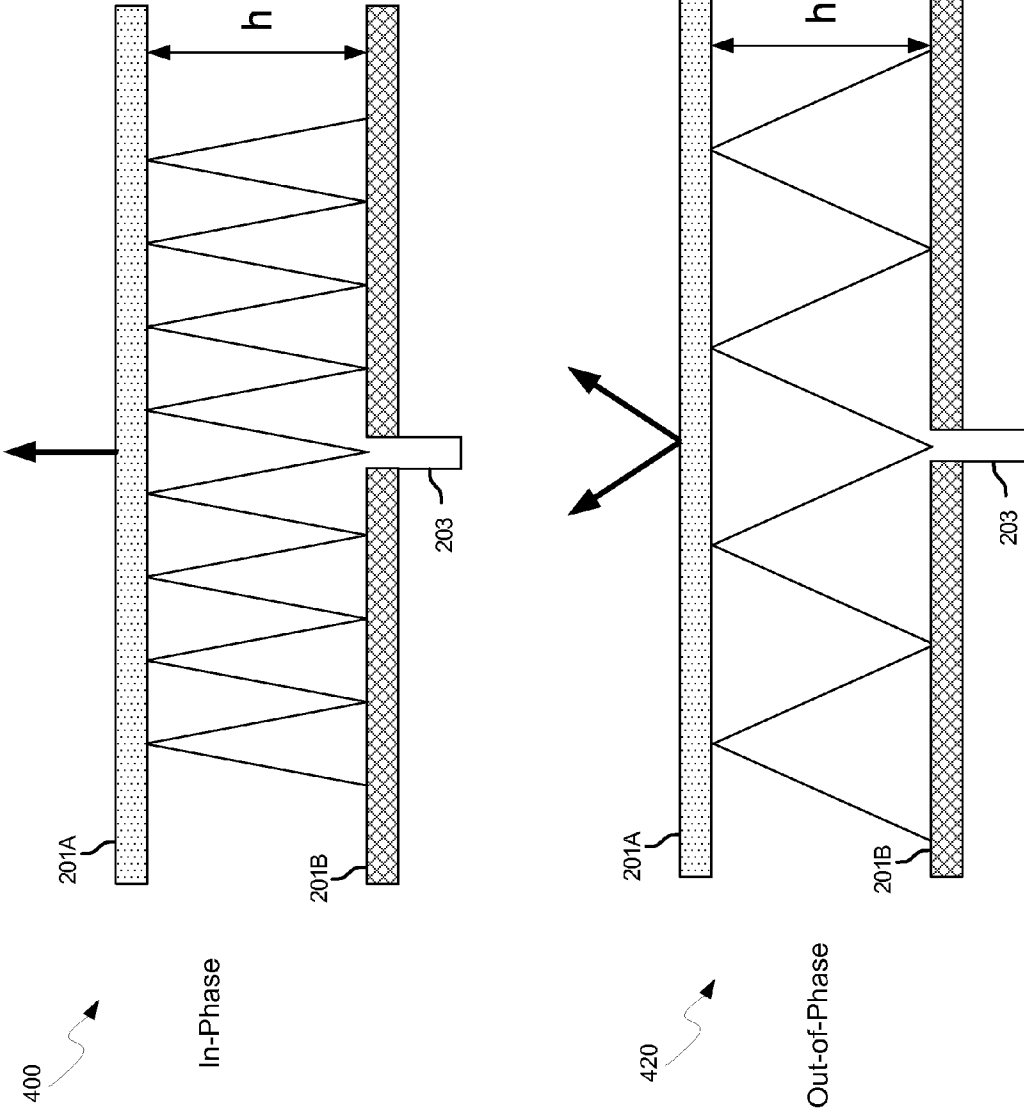


FIG. 4

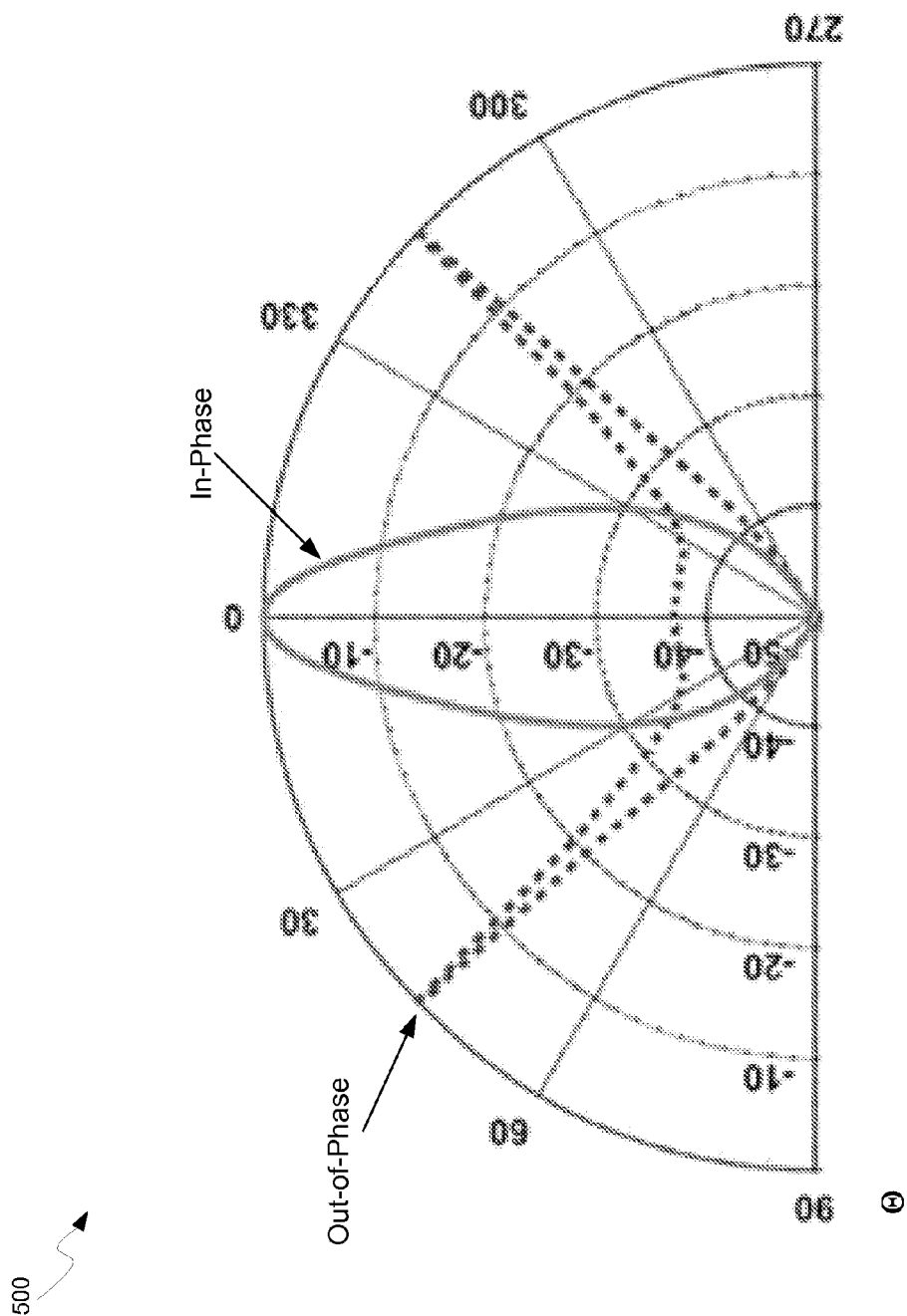


FIG. 5

600

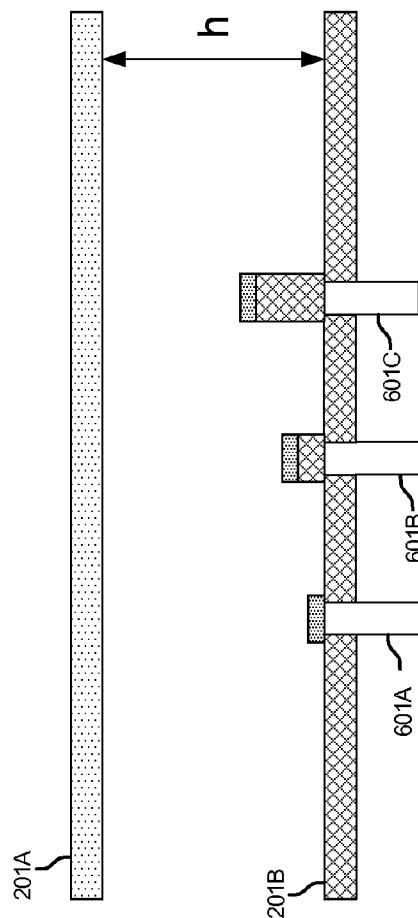


FIG. 6

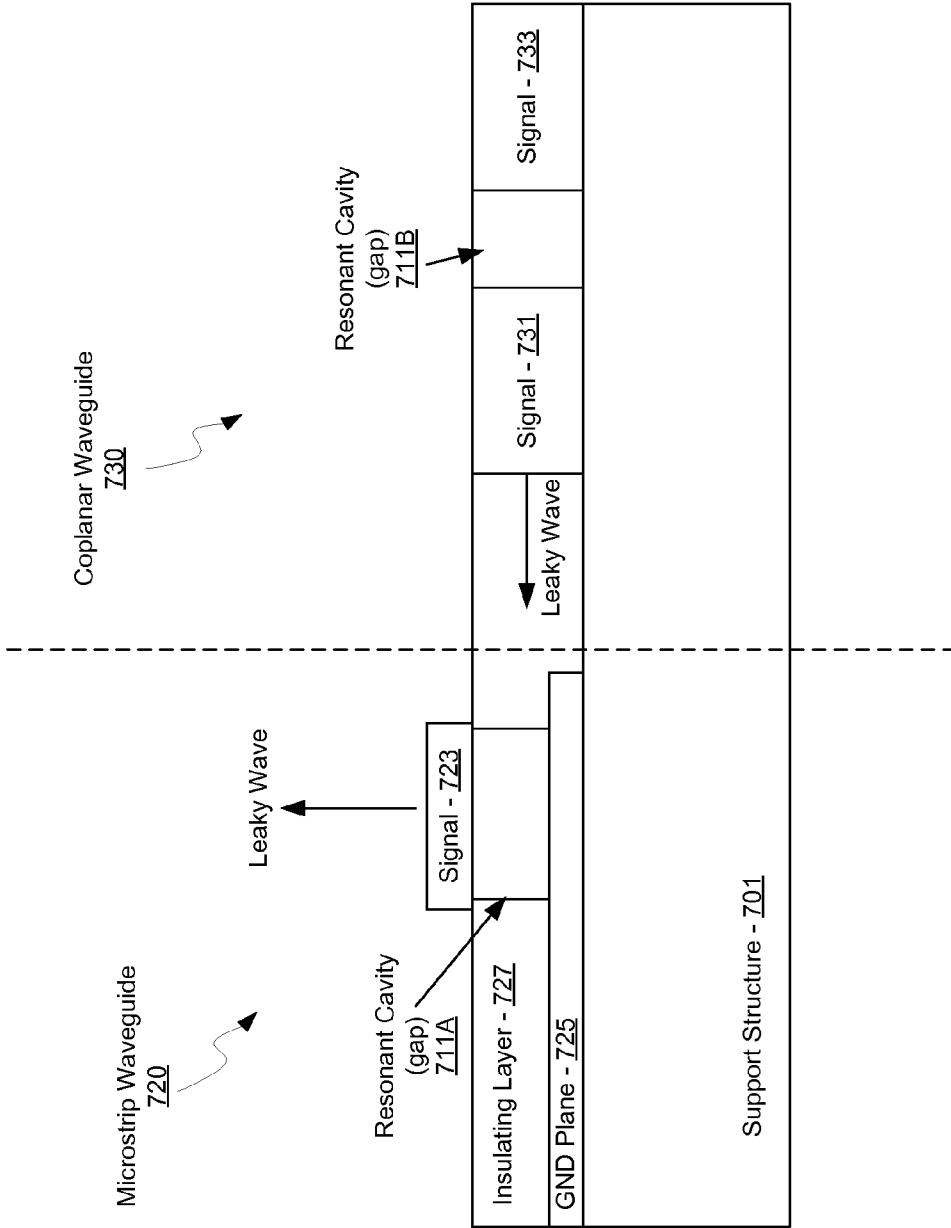


FIG. 7



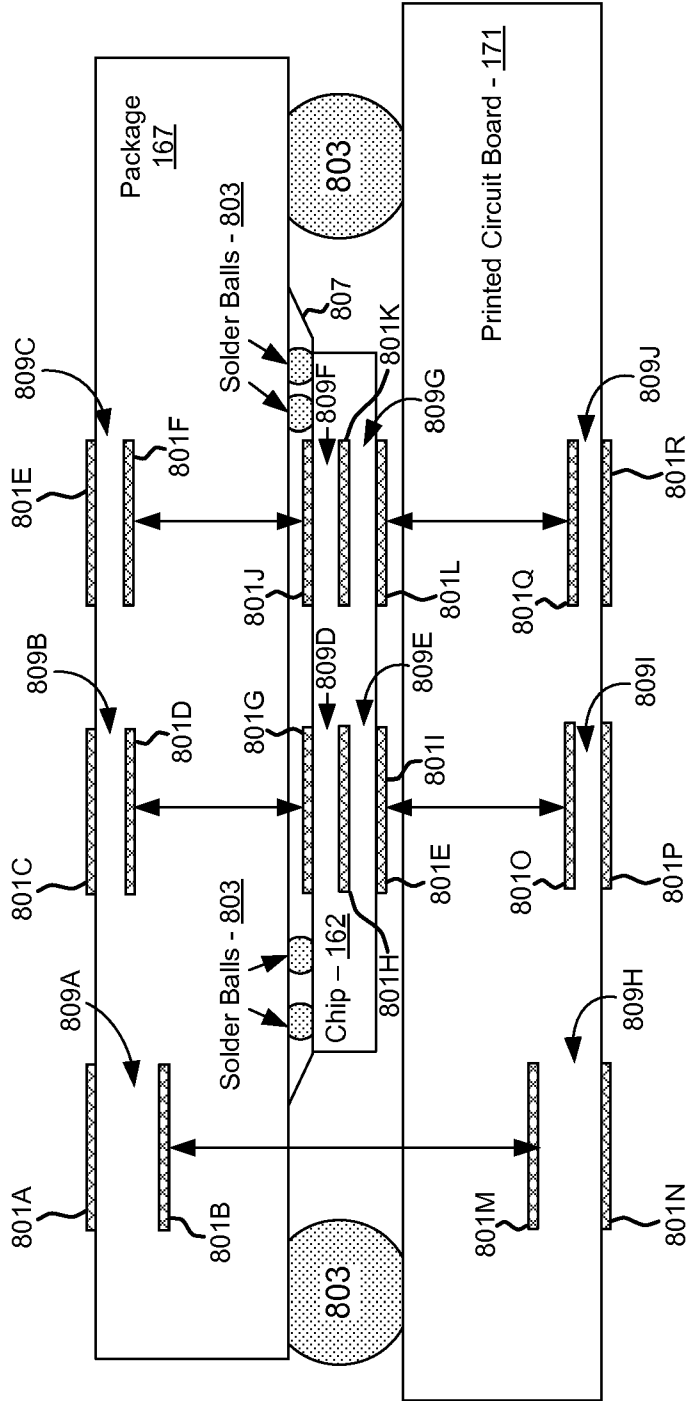


FIG. 8

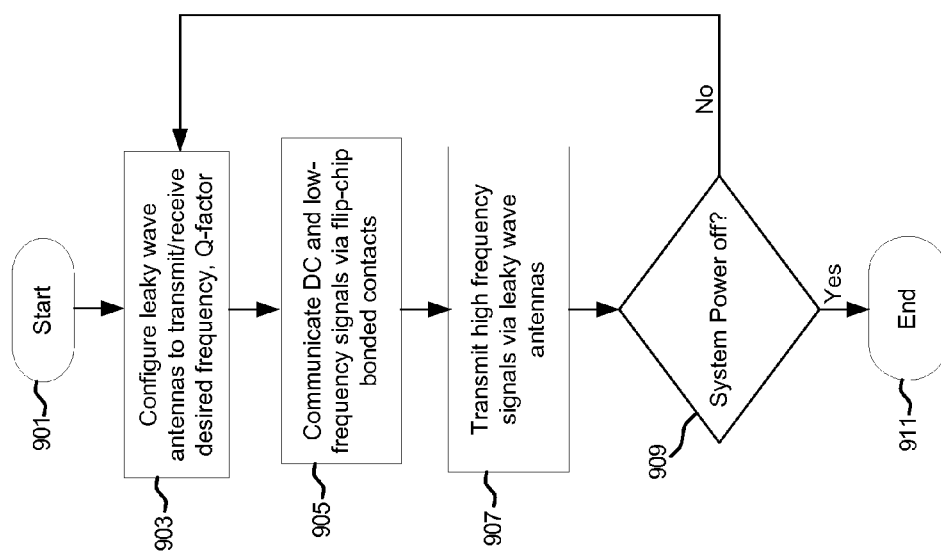


FIG. 9

**METHOD AND SYSTEM FOR  
COMMUNICATING VIA LEAKY WAVE  
ANTENNAS WITHIN A FLIP-CHIP BONDED  
STRUCTURE**

**CROSS-REFERENCE TO RELATED  
APPLICATIONS/INCORPORATION BY  
REFERENCE**

- [0001] This application makes reference to, claims the benefit from, and claims priority to U.S. Provisional Application Ser. No. 61/246,618 filed on Sep. 29, 2009, and U.S. Provisional Application Ser. No. 61/185,245 filed on Jun. 9, 2009.
- [0002] This application also makes reference to:
- [0003] U.S. patent application Ser. No. 12/650,212 filed on Dec. 30, 2009;
- [0004] U.S. patent application Ser. No. 12/650,295 filed on Dec. 30, 2009;
- [0005] U.S. patent application Ser. No. 12/650,277 filed on Dec. 30, 2009;
- [0006] U.S. patent application Ser. No. 12/650,192 filed on Dec. 30, 2009;
- [0007] U.S. patent application Ser. No. 12/650,224 filed on Dec. 30, 2009;
- [0008] U.S. patent application Ser. No. 12/650,176 filed on Dec. 30, 2009;
- [0009] U.S. patent application Ser. No. 12/650,246 filed on Dec. 30, 2009;
- [0010] U.S. patent application Ser. No. 12/650,292 filed on Dec. 30, 2009;
- [0011] U.S. patent application Ser. No. 12/650,324 filed on Dec. 30, 2009;
- [0012] U.S. patent application Ser. No. 12/708,366 filed on Feb. 18, 2010;
- [0013] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21202US02) filed on even date herewith;
- [0014] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21203US02) filed on even date herewith;
- [0015] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21206US02) filed on even date herewith;
- [0016] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21208US02) filed on even date herewith;
- [0017] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21209US02) filed on even date herewith;
- [0018] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21213US02) filed on even date herewith;
- [0019] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21218US02) filed on even date herewith; and
- [0020] U.S. patent application Ser. No. \_\_\_\_\_ (Attorney Docket No. 21220US02) filed on even date herewith.
- [0021] Each of the above stated applications is hereby incorporated herein by reference in its entirety.

**FEDERALLY SPONSORED RESEARCH OR  
DEVELOPMENT**

[0022] [Not Applicable]

**MICROFICHE/COPYRIGHT REFERENCE**

[0023] [Not Applicable]

**FIELD OF THE INVENTION**

[0024] Certain embodiments of the invention relate to wireless communication. More specifically, certain embodiments

of the invention relate to a method and system for communicating via leaky wave antennas within a flip-chip bonded structure.

**BACKGROUND OF THE INVENTION**

[0025] Mobile communications have changed the way people communicate and mobile phones have been transformed from a luxury item to an essential part of every day life. The use of mobile phones is today dictated by social situations, rather than hampered by location or technology. While voice connections fulfill the basic need to communicate, and mobile voice connections continue to filter even further into the fabric of every day life, the mobile Internet is the next step in the mobile communication revolution. The mobile Internet is poised to become a common source of everyday information, and easy, versatile mobile access to this data will be taken for granted.

[0026] As the number of electronic devices enabled for wireline and/or mobile communications continues to increase, significant efforts exist with regard to making such devices more power efficient. For example, a large percentage of communications devices are mobile wireless devices and thus often operate on battery power. Additionally, transmit and/or receive circuitry within such mobile wireless devices often account for a significant portion of the power consumed within these devices. Moreover, in some conventional communication systems, transmitters and/or receivers are often power inefficient in comparison to other blocks of the portable communication devices. Accordingly, these transmitters and/or receivers have a significant impact on battery life for these mobile wireless devices.

[0027] Further limitations and disadvantages of conventional and traditional approaches will become apparent to one of skill in the art, through comparison of such systems with the present invention as set forth in the remainder of the present application with reference to the drawings.

**BRIEF SUMMARY OF THE INVENTION**

[0028] A system and/or method for communicating via leaky wave antennas within a flip-chip bonded structure as shown in and/or described in connection with at least one of the figures, as set forth more completely in the claims.

[0029] Various advantages, aspects and novel features of the present invention, as well as details of an illustrated embodiment thereof, will be more fully understood from the following description and drawings.

**BRIEF DESCRIPTION OF SEVERAL VIEWS OF  
THE DRAWINGS**

[0030] FIG. 1 is a block diagram of an exemplary wireless system with flip-chip bonded leaky wave antennas, which may be utilized in accordance with an embodiment of the invention.

[0031] FIG. 2 is a block diagram illustrating an exemplary leaky wave antenna, in accordance with an embodiment of the invention.

[0032] FIG. 3 is a block diagram illustrating a plan view of exemplary partially reflective surfaces for a leaky wave antenna, in accordance with an embodiment of the invention.

[0033] FIG. 4 is a block diagram illustrating an exemplary phase dependence of a leaky wave antenna, in accordance with an embodiment of the invention.

[0034] FIG. 5 is a block diagram illustrating exemplary in-phase and out-of-phase beam shapes for a leaky wave antenna, in accordance with an embodiment of the invention.

[0035] FIG. 6 is a block diagram illustrating a leaky wave antenna with variable input impedance feed points, in accordance with an embodiment of the invention.

[0036] FIG. 7 is a block diagram illustrating a cross-sectional view of coplanar and microstrip waveguides, in accordance with an embodiment of the invention.

[0037] FIG. 8 is a diagram illustrating a cross-sectional view of flip-chip bonded structures with integrated leaky wave antennas, in accordance with an embodiment of the invention.

[0038] FIG. 9 is a block diagram illustrating exemplary steps for communicating signals via flip-chip bonded structures with integrated leaky wave antennas, in accordance with an embodiment of the invention.

#### DETAILED DESCRIPTION OF THE INVENTION

[0039] Certain aspects of the invention may be found in a method and system for communicating via leaky wave antennas within a flip-chip bonded structure. Exemplary aspects of the invention may comprise communicating RF signals in a wireless device between a plurality of support structures with one or more integrated leaky wave antennas integrated within and/or on the support structures. The support structures may be coupled via flip-chip-bonding. Low-frequency signals may be communicated via contacts defined via the flip-chip bonding. The RF signals may be communicated between the support structures perpendicular to a surface of the structures. The leaky wave antennas may be configured to transmit the wireless signals at a desired angle from the surface of the support structures, which may comprise at least one of: an integrated circuit, an integrated circuit package, and a printed circuit board. The leaky wave antennas may comprise microstrip waveguides where a cavity height of the leaky wave antennas may be configured by controlling spacing between conductive lines in the microstrip waveguides. The leaky wave antennas may comprise coplanar waveguides where a cavity height of the leaky wave antennas may be configured by controlling spacing between conductive lines in the coplanar waveguides. The low-frequency signals may comprise DC bias voltages. The RF signals may be communicated from a single leaky wave antenna to a plurality of leaky wave antennas.

[0040] FIG. 1 is a block diagram of an exemplary wireless system with flip-chip bonded leaky wave antennas, which may be utilized in accordance with an embodiment of the invention. Referring to FIG. 1, the wireless device 150 may comprise an antenna 151, a transceiver 152, a baseband processor 154, a processor 156, a system memory 158, a logic block 160, a chip 162, leaky wave antennas 164A-164C, switches 165A-165C, an external headset port 166, and a package 167. The wireless device 150 may also comprise an analog microphone 168, integrated hands-free (IHF) stereo speakers 170, a printed circuit board 171, a hearing aid compatible (HAC) coil 174, a dual digital microphone 176, a vibration transducer 178, a keypad and/or touchscreen 180, and a display 182.

[0041] The transceiver 152 may comprise suitable logic, circuitry, interface(s), and/or code that may be enabled to modulate and upconvert baseband signals to RF signals for transmission by one or more antennas, which may be represented generically by the antenna 151. The transceiver 152

may also be enabled to downconvert and demodulate received RF signals to baseband signals. The RF signals may be received by one or more antennas, which may be represented generically by the antenna 151, or the leaky wave antennas 164A-164C. Different wireless systems may use different antennas for transmission and reception. The transceiver 152 may be enabled to execute other functions, for example, filtering the baseband and/or RF signals, and/or amplifying the baseband and/or RF signals. Although a single transceiver 152 is shown, the invention is not so limited. Accordingly, the transceiver 152 may be implemented as a separate transmitter and a separate receiver. In addition, there may be a plurality of transceivers, transmitters and/or receivers. In this regard, the plurality of transceivers, transmitters and/or receivers may enable the wireless device 150 to handle a plurality of wireless protocols and/or standards including cellular, WLAN and PAN. Wireless technologies handled by the wireless device 150 may comprise GSM, CDMA, CDMA2000, WCDMA, GMS, GPRS, EDGE, WIMAX, WLAN, 3GPP, UMTS, BLUETOOTH, and ZigBee, for example.

[0042] The baseband processor 154 may comprise suitable logic, circuitry, interface(s), and/or code that may be enabled to process baseband signals for transmission via the transceiver 152 and/or the baseband signals received from the transceiver 152. The processor 156 may be any suitable processor or controller such as a CPU, DSP, ARM, or any type of integrated circuit processor. The processor 156 may comprise suitable logic, circuitry, and/or code that may be enabled to control the operations of the transceiver 152 and/or the baseband processor 154. For example, the processor 156 may be utilized to update and/or modify programmable parameters and/or values in a plurality of components, devices, and/or processing elements in the transceiver 152 and/or the baseband processor 154. At least a portion of the programmable parameters may be stored in the system memory 158.

[0043] Control and/or data information, which may comprise the programmable parameters, may be transferred from other portions of the wireless device 150, not shown in FIG. 1, to the processor 156. Similarly, the processor 156 may be enabled to transfer control and/or data information, which may include the programmable parameters, to other portions of the wireless device 150, not shown in FIG. 1, which may be part of the wireless device 150.

[0044] The processor 156 may utilize the received control and/or data information, which may comprise the programmable parameters, to determine an operating mode of the transceiver 152. For example, the processor 156 may be utilized to select a specific frequency for a local oscillator, a specific gain for a variable gain amplifier, configure the local oscillator and/or configure the variable gain amplifier for operation in accordance with various embodiments of the invention. Moreover, the specific frequency selected and/or parameters needed to calculate the specific frequency, and/or the specific gain value and/or the parameters, which may be utilized to calculate the specific gain, may be stored in the system memory 158 via the processor 156, for example. The information stored in system memory 158 may be transferred to the transceiver 152 from the system memory 158 via the processor 156.

[0045] The system memory 158 may comprise suitable logic, circuitry, interface(s), and/or code that may be enabled to store a plurality of control and/or data information, including parameters needed to calculate frequencies and/or gain, and/or the frequency value and/or gain value. The system

memory 158 may store at least a portion of the programmable parameters that may be manipulated by the processor 156.

[0046] The logic block 160 may comprise suitable logic, circuitry, interface(s), and/or code that may enable controlling of various functionalities of the wireless device 150. For example, the logic block 160 may comprise one or more state machines that may generate signals to control the transceiver 152 and/or the baseband processor 154. The logic block 160 may also comprise registers that may hold data for controlling, for example, the transceiver 152 and/or the baseband processor 154. The logic block 160 may also generate and/or store status information that may be read by, for example, the processor 156. Amplifier gains and/or filtering characteristics, for example, may be controlled by the logic block 160.

[0047] The BT radio/processor 163 may comprise suitable circuitry, logic, interface(s), and/or code that may enable transmission and reception of Bluetooth signals. The BT radio/processor 163 may enable processing and/or handling of BT baseband signals. In this regard, the BT radio/processor 163 may process or handle BT signals received and/or BT signals transmitted via a wireless communication medium. The BT radio/processor 163 may also provide control and/or feedback information to/from the baseband processor 154 and/or the processor 156, based on information from the processed BT signals. The BT radio/processor 163 may communicate information and/or data from the processed BT signals to the processor 156 and/or to the system memory 158. Moreover, the BT radio/processor 163 may receive information from the processor 156 and/or the system memory 158, which may be processed and transmitted via the wireless communication medium a Bluetooth headset, for example

[0048] The CODEC 172 may comprise suitable circuitry, logic, interface(s), and/or code that may process audio signals received from and/or communicated to input/output devices. The input devices may be within or communicatively coupled to the wireless device 150, and may comprise the analog microphone 168, the stereo speakers 170, the hearing aid compatible (HAC) coil 174, the dual digital microphone 176, and the vibration transducer 178, for example. The CODEC 172 may be operable to up-convert and/or down-convert signal frequencies to desired frequencies for processing and/or transmission via an output device. The CODEC 172 may enable utilizing a plurality of digital audio inputs, such as 16 or 18-bit inputs, for example. The CODEC 172 may also enable utilizing a plurality of data sampling rate inputs. For example, the CODEC 172 may accept digital audio signals at sampling rates such as 8 kHz, 11.025 kHz, 12 kHz, 16 kHz, 22.05 kHz, 24 kHz, 32 kHz, 44.1 kHz, and/or 48 kHz. The CODEC 172 may also support mixing of a plurality of audio sources. For example, the CODEC 172 may support audio sources such as general audio, polyphonic ringer, I<sup>2</sup>S FM audio, vibration driving signals, and voice. In this regard, the general audio and polyphonic ringer sources may support the plurality of sampling rates that the audio CODEC 172 is enabled to accept, while the voice source may support a portion of the plurality of sampling rates, such as 8 kHz and 16 kHz, for example.

[0049] The chip 162 may comprise an integrated circuit with multiple functional blocks integrated within, such as the transceiver 152, the processor 156, the baseband processor 154, the BT radio/processor 163, and the CODEC 172. The number of functional blocks integrated in the chip 162 is not limited to the number shown in FIG. 1. Accordingly, any

number of blocks may be integrated on the chip 162 depending on chip space and wireless device 150 requirements, for example. The chip 162 may be flip-chip bonded, for example, to the package 167, as described further with respect to FIG. 8.

[0050] The leaky wave antennas 164A-164C may comprise a resonant cavity with a highly reflective surface and a lower reflectivity surface, and may be integrated in and/or on the chip 162, the package 167, and/or the printed circuit board 171. The lower reflectivity surface may allow the resonant mode to “leak” out of the cavity. The lower reflectivity surface of the leaky wave antennas 164A-164C may be configured with slots in a metal surface, or a pattern of metal patches, as described further in FIGS. 2 and 3. The physical dimensions of the leaky wave antennas 164A-164C may be configured to optimize bandwidth of transmission and/or the beam pattern radiated. By integrating the leaky wave antennas 164A on the chip 162, the package 167, and/or the printed circuit board 171 and flip-chip bonding the chip 162 to the package 167 and the package 167 to the printed circuit board 171, wireless signals may be communicated between devices in the chip 162, the package 167, and the printed circuit board 171.

[0051] In an exemplary embodiment of the invention, the leaky wave antennas 164A-164C may comprise a plurality of leaky wave antennas integrated in and/or on the chip 162, the package 167, and/or printed circuit board 171. The leaky wave antennas 164A-164C may be operable to transmit and/or receive wireless signals at or near 60 GHz, for example, due to the cavity length of the devices being on the order of millimeters. The leaky wave antennas 164A may be configured to transmit in different directions, including in the lateral direction parallel to the surface of the chip 162, the package 167, and the printed circuit board 171, thereby enabling communication between regions of the chip 162, the package 167, and the printed circuit board 171.

[0052] The switches 165A-165C may comprise switches such as CMOS or MEMS switches that may be operable to switch different antennas of the leaky wave antennas 164A-164C to the transceiver 152 and/or switch elements in and/or out of the leaky wave antennas 164A-164C, such as the patches and slots described in FIG. 3. In another embodiment of the invention, the switches 165A-165C may comprise MEMS devices that enable MEMS actuation of reflective surfaces in the leaky wave antennas 164A-164C. Accordingly, the resonant frequency and/or the angle of transmission/reception may be configured for the leaky wave antennas 164A-164C.

[0053] The external headset port 166 may comprise a physical connection for an external headset to be communicatively coupled to the wireless device 150. The analog microphone 168 may comprise suitable circuitry, logic, interface(s), and/or code that may detect sound waves and convert them to electrical signals via a piezoelectric effect, for example. The electrical signals generated by the analog microphone 168 may comprise analog signals that may require analog to digital conversion before processing.

[0054] The package 167 may comprise a ceramic package, a circuit board, or other support structure for the chip 162 and other components of the wireless device 150. In this regard, the chip 162 may be bonded to the package 167. The package 167 may comprise insulating and conductive material, for example, and may provide isolation between electrical components mounted on the package 167.

[0055] The printed circuit board 171 may comprise an essentially electrically insulating material with conductive traces integrated within and/or on the surface for the inter-connection of devices affixed to the printed circuit board 171. For example, the package 167 may be affixed to the printed circuit board 171 utilizing flip-chip bonding. In addition, the leaky wave antennas 164C and the switches 165C may be integrated in and/or on the printed circuit board 171 to enable communication of RF signals between the printed circuit board 171 and devices in the chip 162 and the package 167. The number of devices on the printed circuit board 171 is not limited to the number shown in FIG. 1. Accordingly, any number of chips, packages, and other devices may be integrated, depending on space requirements and desired functionality.

[0056] The stereo speakers 170 may comprise a pair of speakers that may be operable to generate audio signals from electrical signals received from the CODEC 172. The HAC coil 174 may comprise suitable circuitry, logic, and/or code that may enable communication between the wireless device 150 and a T-coil in a hearing aid, for example. In this manner, electrical audio signals may be communicated to a user that utilizes a hearing aid, without the need for generating sound signals via a speaker, such as the stereo speakers 170, and converting the generated sound signals back to electrical signals in a hearing aid, and subsequently back into amplified sound signals in the user's ear, for example.

[0057] The dual digital microphone 176 may comprise suitable circuitry, logic, interface(s), and/or code that may be operable to detect sound waves and convert them to electrical signals. The electrical signals generated by the dual digital microphone 176 may comprise digital signals, and thus may not require analog to digital conversion prior to digital processing in the CODEC 172. The dual digital microphone 176 may enable beamforming capabilities, for example.

[0058] The vibration transducer 178 may comprise suitable circuitry, logic, interface(s), and/or code that may enable notification of an incoming call, alerts and/or message to the wireless device 150 without the use of sound. The vibration transducer may generate vibrations that may be in synch with, for example, audio signals such as speech or music.

[0059] In operation, control and/or data information, which may comprise the programmable parameters, may be transferred from other portions of the wireless device 150, not shown in FIG. 1, to the processor 156. Similarly, the processor 156 may be enabled to transfer control and/or data information, which may include the programmable parameters, to other portions of the wireless device 150, not shown in FIG. 1, which may be part of the wireless device 150.

[0060] The processor 156 may utilize the received control and/or data information, which may comprise the programmable parameters, to determine an operating mode of the transceiver 152. For example, the processor 156 may be utilized to select a specific frequency for a local oscillator, a specific gain for a variable gain amplifier, configure the local oscillator and/or configure the variable gain amplifier for operation in accordance with various embodiments of the invention. Moreover, the specific frequency selected and/or parameters needed to calculate the specific frequency, and/or the specific gain value and/or the parameters, which may be utilized to calculate the specific gain, may be stored in the system memory 158 via the processor 156, for example. The

information stored in system memory 158 may be transferred to the transceiver 152 from the system memory 158 via the processor 156.

[0061] The CODEC 172 in the wireless device 150 may communicate with the processor 156 in order to transfer audio data and control signals. Control registers for the CODEC 172 may reside within the processor 156. The processor 156 may exchange audio signals and control information via the system memory 158. The CODEC 172 may up-convert and/or down-convert the frequencies of multiple audio sources for processing at a desired sampling rate.

[0062] The leaky wave antennas 164A-164C may be operable to transmit and/or receive wireless signals between the chip 162, the package 167, and the printed circuit board 171. Resonant cavities may be configured between reflective surfaces in and/or on the chip 162, the package 167, and/or the printed circuit board 171 so that signals may be transmitted and/or received from any location without requiring large areas needed for conventional antennas and associated circuitry. Coplanar waveguide structures may be utilized to enable the communication of signals in the horizontal direction within the chip 162, the package 167, and/or the printed circuit board 171.

[0063] The cavity height of the leaky wave antennas 164A-164C may be configured to control the frequency of the signals that may be transmitted and/or received. Accordingly, the reflective surfaces may be controlled to provide different heights in the chip 162, the package 167, and/or the printed circuit board 171, thereby configuring leaky wave antennas with different resonant frequencies.

[0064] The leaky wave antennas 164A may be operable to transmit and/or receive signals to and from the chip 162. In this manner, high frequency traces to an external antenna, such as the antenna 151, may be reduced and/or eliminated for higher frequency signals.

[0065] Different frequency signals may be transmitted and/or received by the leaky wave antennas 164A-164C by selectively coupling the transceiver 152 to leaky wave antennas with different cavity heights. For example, a leaky wave antenna with reflective surfaces on the top and the bottom of the printed circuit board 171 may have the largest cavity height, and thus provide the lowest resonant frequency. Conversely, a leaky wave antenna with both reflective surfaces in the same plane of the chip 162, as in a coplanar waveguide configuration, for example, may provide a higher resonant frequency.

[0066] FIG. 2 is a block diagram illustrating an exemplary leaky wave antenna, in accordance with an embodiment of the invention. Referring to FIG. 2, there is shown the leaky wave antennas 164A-164C comprising a partially reflective surface 201A, a reflective surface 201B, and a feed point 203. The space between the partially reflective surface 201A and the reflective surface 201B may be filled with dielectric material, for example, and the height,  $h$ , between the partially reflective surface 201A and the reflective surface 201B may be utilized to configure the frequency of transmission of the leaky wave antennas 164A-164C. In another embodiment of the invention, an air gap may be integrated in the space between the partially reflective surface 201A and the reflective surface 201B to enable MEMS actuation. There is also shown (micro-electromechanical systems) MEMS bias voltages,  $+V_{MEMS}$  and  $-V_{MEMS}$ .

[0067] The feed point 203 may comprise an input terminal for applying an input voltage to the leaky wave antennas

**164A-164C.** The invention is not limited to a single feed point **203**, as there may be any amount of feed points for different phases of signal or a plurality of signal sources, for example, to be applied to the leaky wave antennas **164A-164C**.

**[0068]** In an embodiment of the invention, the height,  $h$ , may be one-half the wavelength of the desired transmitted mode from the leaky wave antennas **164A-164C**. In this manner, the phase of an electromagnetic mode that traverses the cavity twice may be coherent with the input signal at the feed point **203**, thereby configuring a resonant cavity known as a Fabry-Perot cavity. The magnitude of the resonant mode may decay exponentially in the lateral direction from the feed point **203**, thereby reducing or eliminating the need for confinement structures to the sides of the leaky wave antennas **164**. The input impedance of the leaky wave antennas **164A-164C** may be configured by the vertical placement of the feed point **203**, as described further in FIG. 6.

**[0069]** In operation, a signal to be transmitted via a power amplifier in the transceiver **152** may be communicated to the feed point **203** of the leaky wave antennas **164A-164C** with a frequency  $f$ . The cavity height,  $h$ , may be configured to correlate to one half the wavelength of a harmonic of the signal of frequency  $f$ . The signal may traverse the height of the cavity and may be reflected by the partially reflective surface **201A**, and then traverse the height back to the reflective surface **201 B**. Since the wave will have travelled a distance corresponding to a full wavelength, constructive interference may result and a resonant mode may thereby be established.

**[0070]** Leaky wave antennas may enable the configuration of high gain antennas without the need for a large array of antennas which require a complex feed network and suffer from loss due to feed lines. The leaky wave antennas **164A-164C** may be operable to transmit and/or receive wireless signals via conductive layers in and/or on chip **162**, the package **167**, and the printed circuit board **171**. In this manner, the resonant frequency of the cavity may cover a wider range due to the larger size of the printed circuit board **171**, compared to the package **167**, and similarly compared to the chip **162**, without requiring large areas needed for conventional antennas and associated circuitry. Accordingly, RF signals may be communicated between the chip **162**, the package **167**, and the printed circuit board **171**.

**[0071]** In an exemplary embodiment of the invention, the frequency of transmission and/or reception of the leaky wave antennas **164A-164C** may be configured by selecting one of the leaky wave antennas **164A-164C** with the appropriate cavity height for the desired frequency and with an appropriate direction of transmission and/or reception to enable communication between desired locations. Leaky wave antennas integrated on the chip **162**, the package **167**, and the printed circuit board **171** may comprise coplanar waveguide structures, either on a surface and/or integrated within the chip **162**, the package **167**, and the printed circuit board **171**, such that wireless signals may be communicated in a horizontal direction, enabling wireless communication between regions of the structure. Additionally, leaky wave antennas may be integrated with the direction of the leaked signal coming out of the surface of the chip **162**, thereby enabling communication between the chip **162** and external devices on the package **167**, the printed circuit board **171**, and/or other external devices.

**[0072]** In another embodiment of the invention, the cavity height,  $h$ , may be configured by MEMS actuation. For example, the bias voltages  $+V_{MEMS}$  and  $-V_{MEMS}$  may deflect

one or both of the reflective surfaces **201A** and **201 B** compared to zero bias, thereby configuring the resonant frequency of the cavity.

**[0073]** FIG. 3 is a block diagram illustrating a plan view of exemplary partially reflective surfaces for a leaky wave antenna, in accordance with an embodiment of the invention. Referring to FIG. 3, there is shown a partially reflective surface **300** comprising periodic slots in a metal surface, and a partially reflective surface **320** comprising periodic metal patches. The partially reflective surfaces **300/320** may comprise different embodiments of the partially reflective surface **201A** described with respect to FIG. 2.

**[0074]** The spacing, dimensions, shape, and orientation of the slots and/or patches in the partially reflective surfaces **300/320** may be utilized to configure the bandwidth, and thus Q-factor, of the resonant cavity defined by the partially reflective surfaces **300/320** and a reflective surface, such as the reflective surface **201B**, described with respect to FIG. 2. The partially reflective surfaces **300/320** may thus comprise frequency selective surfaces due to the narrow bandwidth of signals that may leak out of the structure as configured by the slots and/or patches.

**[0075]** The spacing between the patches and/or slots may be related to wavelength of the signal transmitted and/or received, which may be somewhat similar to beamforming with multiple antennas. The length of the slots and/or patches may be several times larger than the wavelength of the transmitted and/or received signal or less, for example, since the leakage from the slots and/or regions surround the patches may add up, similar to beamforming with multiple antennas.

**[0076]** In an embodiment of the invention, the slots/patches may be configured via CMOS and/or micro-electromechanical system (MEMS) switches, such as the switches **165A-165C** described with respect to FIG. 1, to tune the Q of the resonant cavity. The slots and/or patches may be configured in conductive layers in and/or on the chip **162**, the package **167**, and the printed circuit board **171**, and may be shorted together or switched open utilizing the switches **165A-165C**. In this manner, RF signals, such as 60 GHz signals, for example, may be transmitted from various locations in the chip **162**, the package **167**, and the printed circuit board **171** without the need for additional circuitry and conventional antennas with their associated circuitry that require valuable space.

**[0077]** In another embodiment of the invention, the slots or patches may be configured in conductive layers in a vertical plane of the chip **162**, the package **167**, and/or the printed circuit board **171**, thereby enabling the communication of wireless signals in a horizontal direction in the structure.

**[0078]** FIG. 4 is a block diagram illustrating an exemplary phase dependence of a leaky wave antenna, in accordance with an embodiment of the invention. Referring to FIG. 4, there is shown a leaky wave antenna comprising the partially reflective surface **201A**, the reflective surface **201B**, and the feed point **203**. In-phase condition **400** illustrates the relative beam shape transmitted by the leaky wave antennas **164A-164C** when the frequency of the signal communicated to the feed point **203** matches that of the resonant cavity as defined by the cavity height,  $h$ , and the dielectric constant of the material between the reflective surfaces.

**[0079]** Similarly, out-of-phase condition **420** illustrates the relative beam shape transmitted by the leaky wave antenna **164A-164C** when the frequency of the signal communicated to the feed point **203** does not match that of the resonant cavity. The resulting beam shape may be conical, as opposed

to a single main vertical node. These are illustrated further with respect to FIG. 5. The leaky wave antennas 164A-164C may be integrated at various heights in the chip 162, the package 167, and the printed circuit board 171, thereby providing a plurality of transmission and reception sites in the structure with varying resonant frequency. In addition, a coplanar structure may be utilized to configure leaky wave antennas in the chip 162, the package 167, and/or the printed circuit board 171, thereby enabling communication of wireless signals in the horizontal plane of the structure.

[0080] By configuring the leaky wave antennas 164A-164C for in-phase and out-of-phase conditions, signals possessing different characteristics may be directed out of the chip 162, the package 167, and/or printed circuit board 171 in desired directions. In an exemplary embodiment of the invention, the angle at which signals may be transmitted by a leaky wave antenna may be dynamically controlled so that signal may be directed to desired receiving leaky wave antennas. In another embodiment of the invention, the leaky wave antennas 164A-164C may be operable to receive RF signals, such as 60 GHz signals, for example. The direction in which the signals are received may be configured by the in-phase and out-of-phase conditions.

[0081] FIG. 5 is a block diagram illustrating exemplary in-phase and out-of-phase beam shapes for a leaky wave antenna, in accordance with an embodiment of the invention. Referring to FIG. 5, there is shown a plot 500 of transmitted signal beam shape versus angle,  $\Theta$ , for the in-phase and out-of-phase conditions for a leaky wave antenna.

[0082] The In-phase curve in the plot 500 may correlate to the case where the frequency of the signal communicated to a leaky wave antenna matches the resonant frequency of the cavity. In this manner, a single vertical main node may result. In instances where the frequency of the signal at the feed point is not at the resonant frequency, a double, or conical-shaped node may be generated as shown by the Out-of-phase curve in the plot 500. By configuring the leaky wave antennas for in-phase and out-of-phase conditions, signals may be directed out of the chip 162, the package 167, and/or the printed circuit board 171 in desired directions.

[0083] In another embodiment of the invention, the leaky wave antennas 164A-164C may be operable to receive wireless signals, and may be configured to receive from a desired direction via the in-phase and out-of-phase configurations.

[0084] FIG. 6 is a block diagram illustrating a leaky wave antenna with variable input impedance feed points, in accordance with an embodiment of the invention. Referring to FIG. 6, there is shown a leaky wave antenna 600 comprising the partially reflective surface 201A and the reflective surface 201B. There is also shown feed points 601A-601C. The feed points 601A-601C may be located at different positions along the height,  $h$ , of the cavity thereby configuring different impedance points for the leaky wave antenna.

[0085] In this manner, a leaky wave antenna may be utilized to couple to a plurality of power amplifiers, low-noise amplifiers, and/or other circuitry with varying output or input impedances. Similarly, by integrating leaky wave antennas in conductive layers in the chip 162, or integrating antennas in the printed circuit board 171 and/or the package 167 and flip-chip bonding to the chip 162, the impedance of the leaky wave antenna may be matched to the power amplifier or low-noise amplifier without impedance variations that may result with conventional antennas and their proximity or distance to associated driver electronics. Similarly, by integrat-

ing reflective and partially reflective surfaces with varying cavity heights and varying feed points, leaky wave antennas with different impedances and resonant frequencies may be enabled.

[0086] FIG. 7 is a block diagram illustrating a cross-sectional view of coplanar and microstrip waveguides, in accordance with an embodiment of the invention. Referring to FIG. 7, there is shown a microstrip waveguide 720, a coplanar waveguide 730, and a support structure 701. The microstrip waveguide 720 may comprise signal conductive lines 723, a ground plane 725, a gap 711A, an insulating layer 727 and a substrate 729. The coplanar waveguide 730 may comprise signal conductive lines 731 and 733, a gap 711B, and the insulating layer 727. The support structure 701 may comprise the chip 162, the package 167, or the printed circuit board 171.

[0087] The signal conductive lines 723, 731, and 733 may comprise metal traces or layers deposited in and/or on the insulating layer 727. In another embodiment of the invention, the signal conductive lines 723, 731, and 733 may comprise poly-silicon or other conductive material. The separation and the voltage potential between the signal conductive line 723 and the ground plane 725 may determine the electric field generated therein. In addition, the dielectric constant of the insulating layer 727 may also determine the electric field between the signal conductive line 723 and the ground plane 725.

[0088] The insulating layer 727 may comprise  $\text{SiO}_2$  or other insulating material that may provide a high resistance layer between the signal conductive line 723 and the ground plane 725, and the signal conductive lines 731 and 733. In addition, the electric field between the signal conductive line 723 and the ground plane 725 may be dependent on the dielectric constant of the insulating layer 727.

[0089] The thickness and the dielectric constant of the insulating layer 727 and/or the gaps 711A and 711B may determine the electric field strength generated by the applied signal. The resonant cavity thickness of a leaky wave antenna may be dependent on the spacing between the signal conductive line 723 and the ground plane 725, or the signal conductive lines 731 and 733, for example. In an exemplary embodiment of the invention, the insulating layer 727 may be removed in localized regions in the microstrip waveguide 720 and the coplanar waveguide 730 to configure the gaps 711A and 711B, thereby allowing for MEMS deflection of the conductive layers and configuring of the height of the resonant cavity. The gaps 711A and 711B may extend completely between the signal conductive layer 723 and the ground plane 725 or the signal conductive lines 731 and 733, or may extend only a portion of the distance.

[0090] The signal conductive lines 731 and 733, and the signal conductive line 723 and the ground plane 725 may define resonant cavities for leaky wave antennas. Each layer may comprise a reflective surface or a partially reflective surface depending on the pattern of conductive material. For example, a partially reflective surface may be configured by alternating conductive and insulating material in a 1-dimensional or 2-dimensional pattern. In this manner, signals may be directed out of, or received into, a surface of the support structure 701, as illustrated with the microstrip waveguide 720. In another embodiment of the invention, signals may be communicated in the horizontal plane of the support structure 701 utilizing the coplanar waveguide 730.



[0091] The support structure 701 may provide mechanical support for the microstrip waveguide 720, the coplanar waveguide 730, and other devices that may be integrated within. In an embodiment of the invention, the support structure 701 may comprise Si, GaAs, sapphire, InP, GaO, ZnO, CdTe, CdZnTe, ceramics, polytetrafluoroethylene, and/or Al<sub>2</sub>O<sub>3</sub>, for example, or any other substrate material that may be suitable for integrating microstrip structures.

[0092] In operation, a bias and/or a signal voltage may be applied across the signal conductive line 723 and the ground plane 725, and/or the signal conductive lines 731 and 733. The thickness of a leaky wave antenna resonant cavity may be dependent on the distance between the conductive lines in the microstrip waveguide 720 and/or the coplanar transmission waveguide 730.

[0093] By alternating patches of conductive material with insulating material, or slots of conductive material in dielectric material, a partially reflective surface may result, which may allow a signal to “leak out” in that direction, as shown by the Leaky Wave arrows in FIG. 7. In this manner, wireless signals may be directed out of the surface plane of the support structure 701, or parallel to the surface of the support structure 701.

[0094] FIG. 8 is a diagram illustrating a cross-sectional view of flip-chip bonded structures with integrated leaky wave antennas, in accordance with an embodiment of the invention. Referring to FIG. 8, there is shown metal layers 801A-801R, solder balls 803, thermal epoxy 807, and leaky wave antennas 809A-809J. The chip 162, the package 167, and the printed circuit board 171 may be as described previously.

[0095] The chip 162, or integrated circuit, may comprise one or more components and/or systems within the wireless system 150. The chip 162 may be bump-bonded or flip-chip bonded to the package 167 utilizing the solder balls 803. In this manner, wire bonds connecting the chip 162 to the package 167 may be eliminated, thereby reducing and/or eliminating uncontrollable stray inductances due to wire bonds, for example. In addition, the thermal conductance out of the chip 162 may be greatly improved utilizing the solder balls 803 and the thermal epoxy 807. The thermal epoxy 807 may be electrically insulating but thermally conductive to allow for thermal energy to be conducted out of the chip 162 to the much larger thermal mass of the package 167.

[0096] The metal layers 801A-801R may comprise deposited metal layers utilized to delineate leaky wave antennas in and/or on the chip 162, the package 167, and the printed circuit board 171. The metal layers 801A-801R may be utilized to communicate signals between devices in the chip 162, the package 167, and/or the printed circuit board 172, and/or to external devices via leaky wave antennas. In addition, the leaky wave antennas 809A-809J may comprise conductive and insulating layers integrated in and/or on the chip 162, the package 167, and/or the printed circuit board 172 to enable communication of signals horizontally in the plane of the structure, as illustrated by the coplanar waveguide 730 described with respect to FIG. 7.

[0097] In an embodiment of the invention, the spacing between pairs of metal layers, for example 801A and 801B, 801C and 801D, 801E and 801F, 801G and 801H, 801H and 801I, 801J and 801K, 801K and 801L, 801M and 801N, 801O and 801P, and 801Q and 801R, may define vertical resonant cavities of the leaky wave antennas 809A-809J, respectively. At least one of the metal layers in a leaky wave antenna may

comprise a partially reflective surface, as shown in FIGS. 2 and 3, for example, and may enable the resonant electromagnetic mode in the cavity to leak out from that surface. In this manner, leaky wave antennas may be operable to communicate wireless signals between leaky wave antennas in and/or on the chip 162, the package 167, and/or the printed circuit board 171, and/or to external devices.

[0098] The metal layers 801H and 801K may be shared by two leaky wave antennas, such as the leaky wave antennas 809D and 809E, and 809F and 809G. In another embodiment of the invention, the metal layers 801H and 801K may be eliminated, thereby making the leaky wave antennas the entire thickness of the chip 162.

[0099] The metal layers 801A-801R may comprise microstrip structures as described with respect to FIG. 7. The region between the metal layers 801A-801R may comprise a resistive material that may provide electrical isolation between the metal layers 801A-801R thereby creating a resonant cavity.

[0100] The number of metal layers is not limited to the number of metal layers 801A-801F shown in FIG. 8. Accordingly, there may be any number of layers embedded within and/or on the chip 162, the package 167, and/or the printed circuit board 171, depending on the number of leaky wave antennas, traces, waveguides and other devices fabricated.

[0101] The solder balls 803 may comprise spherical balls of metal to provide electrical, thermal and physical contact between the chip 162, the package 167, and/or the printed circuit board 171. In making the contact with the solder balls 803, the chip 162 and/or the package 167 may be pressed with enough force to squash the metal spheres somewhat, and may be performed at an elevated temperature to provide suitable electrical resistance and physical bond strength. The thermal epoxy 807 may fill the volume between the solder balls 803 and may provide a high thermal conductance path for heat transfer out of the chip 162.

[0102] In operation, the chip 162 may comprise an RF front end, such as the RF transceiver 152, described with respect to FIG. 1, and may be utilized to transmit and/or receive RF signals, at 60 GHz, for example. The chip 162 may be electrically coupled to the package 167, and the package 167 may be electrically coupled to the printed circuit board 171 via flip-chip bonding. In instances where high frequency signals, 60 GHz or greater, for example, may be communicated between the chip 162, the package 167, the printed circuit board 171, and/or external devices, leaky wave antennas may be utilized. Accordingly, the leaky wave antennas 809A-809J integrated on or within the chip 162, the package 167, and/or the printed circuit board 171 may be enabled to communicate signals from regions or sections within the chip 162, the package 167, and/or the printed circuit board 171 to other leaky wave antennas in the chip 162, the package 167, and/or the printed circuit board 171.

[0103] In another embodiment of the invention, leaky wave antennas may comprise coplanar waveguide structures, for example, and may be operable to communicate wireless signals in the horizontal plane, parallel to the surface of the chip 162, the package 167, and/or the integrated circuit board 171. In this manner, signals may be communicated between disparate regions of the chip 162, the package 167, and/or the integrated circuit board 171 without the need to run lossy electrical signal lines. The leaky wave antennas 809A-809J may comprise microstrip waveguide structures, for example, that may be operable to wirelessly communicate signals perpendicular to the plane of the supporting structure, such as the

chip 162, the package 167, and the printed circuit board 171. In this manner, wireless signals may be communicated between the chip 162, the package 167, and the printed circuit board 171.

[0104] The integration of leaky wave antennas in the chip 162, the package 167, and the printed circuit board 171 and electrical coupling via flip-chip bonding may result in the reduction of stray impedances when compared to wire-bonded connections between structures as in conventional systems, particularly for higher frequencies, such as 60 GHz. By flip-chip bonding structures with integrated leaky wave antennas, high frequency signals may be communicated between via the leaky wave antennas 809A-809J, while DC and low frequency signals may be communicated via bump-bonds such as the solder balls 803. In this manner, volume requirements may be reduced and performance may be improved due to lower losses and accurate control of impedances via switches in the chip 162 or on the package 167, for example.

[0105] In an embodiment of the invention, leaky wave antennas may be integrated in different structures, such as the chip 162, the package 167, and the printed circuit board 171, with matching resonant frequency leaky wave antennas, such that only sections of circuits that are desired to receive signals may be configured to receive them. For example, the leaky wave antennas 809A and 809H may have the same cavity height and thus resonant frequency, as compared to the other leaky wave antennas, thereby enabling an exclusive communication link between these antennas.

[0106] In another embodiment of the invention, the leaky wave antennas 809A-809J may be configured to communicate RF signal at an angle from the vertical by adjusting the frequency of the feed signal, as described with respect to FIGS. 4 and 5. In this manner, the leaky wave antennas 809A-809J may be operable to communicate with a plurality of antennas.

[0107] FIG. 9 is a block diagram illustrating exemplary steps for communicating signals via flip-chip bonded structures with integrated leaky wave antennas, in accordance with an embodiment of the invention. Referring to FIG. 9, in step 903 after start step 901, one or more leaky wave antennas integrated may be configured to communicate wireless signals by coupling to RF power amplifiers or low noise amplifiers, for example. In step 905, DC and/or low frequency signals may be communicated between structures via bump-bonded interconnects. In step 907, high frequency signals may be communicated between the chip, the package, and/or the printed circuit board via leaky wave antennas. In step 909, in instances where the wireless device 150 is to be powered down, the exemplary steps may proceed to end step 911. In step 909, in instances where the wireless device 150 is not to be powered down, the exemplary steps may proceed to step 903 to configure the leaky wave antenna at a desired frequency.

[0108] In an embodiment of the invention, a method and system are disclosed for communicating RF signals in a wireless device 150 between a plurality of support structures 162, 167, and 171 with one or more integrated leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J integrated in the support structures 162, 167, and 171. The support structures 162, 167, and 171 may be coupled via flip-chip-bonding. Low-frequency signals may be communicated via contacts 803 defined via the flip-chip bonding. The RF signals may be communicated between the support structures 162, 167, and

171 perpendicular to a surface of the structures 162, 167, and 171. The leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J may be configured to transmit the wireless signals at a desired angle from the surface of the support structures 162, 167, and 171, which may comprise at least one of: an integrated circuit 162, an integrated circuit package 167, and a printed circuit board 171.

[0109] The leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J may comprise microstrip waveguides 720 where a cavity height of the leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J may be configured by controlling spacing between conductive lines 723 and 725 in the microstrip waveguides 720. The leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J may comprise coplanar waveguides 730 where a cavity height of the leaky wave antennas 164A-164C, 400, 420, 600, and 809A-809J may be configured by controlling spacing between conductive lines 731 and 733 in the coplanar waveguides 730. The low-frequency signals may comprise DC bias voltages. The RF signals may be communicated from a single leaky wave antenna to a plurality of leaky wave antennas.

[0110] Other embodiments of the invention may provide a non-transitory computer readable medium and/or storage medium, and/or a non-transitory machine readable medium and/or storage medium, having stored thereon, a machine code and/or a computer program having at least one code section executable by a machine and/or a computer, thereby causing the machine and/or computer to perform the steps as described herein for communicating via leaky wave antennas within a flip-chip bonded structure.

[0111] Accordingly, aspects of the invention may be realized in hardware, software, firmware or a combination thereof. The invention may be realized in a centralized fashion in at least one computer system or in a distributed fashion where different elements are spread across several interconnected computer systems. Any kind of computer system or other apparatus adapted for carrying out the methods described herein is suited. A typical combination of hardware, software and firmware may be a general-purpose computer system with a computer program that, when being loaded and executed, controls the computer system such that it carries out the methods described herein.

[0112] One embodiment of the present invention may be implemented as a board level product, as a single chip, application specific integrated circuit (ASIC), or with varying levels integrated on a single chip with other portions of the system as separate components. The degree of integration of the system will primarily be determined by speed and cost considerations. Because of the sophisticated nature of modern processors, it is possible to utilize a commercially available processor, which may be implemented external to an ASIC implementation of the present system. Alternatively, if the processor is available as an ASIC core or logic block, then the commercially available processor may be implemented as part of an ASIC device with various functions implemented as firmware.

[0113] The present invention may also be embedded in a computer program product, which comprises all the features enabling the implementation of the methods described herein, and which when loaded in a computer system is able to carry out these methods. Computer program in the present context may mean, for example, any expression, in any language, code or notation, of a set of instructions intended to cause a system having an information processing capability

to perform a particular function either directly or after either or both of the following: a) conversion to another language, code or notation; b) reproduction in a different material form. However, other meanings of computer program within the understanding of those skilled in the art are also contemplated by the present invention.

[0114] While the invention has been described with reference to certain embodiments, it will be understood by those skilled in the art that various changes may be made and equivalents may be substituted without departing from the scope of the present invention. In addition, many modifications may be made to adapt a particular situation or material to the teachings of the present invention without departing from its scope. Therefore, it is intended that the present invention not be limited to the particular embodiments disclosed, but that the present invention will include all embodiments falling within the scope of the appended claims.

What is claimed is:

- 1. A method for communication, the method comprising: in a wireless device comprising one or more leaky wave antennas integrated within and/or on a plurality of support structures, said support structures being coupled via flip-chip-bonding: communicating RF signals between said support structures via said one or more integrated leaky wave antennas; and communicating low-frequency signals via contacts defined via said flip-chip bonding.
- 2. The method according to claim 1, comprising communicating said RF signals between said support structures perpendicular to a surface of said support structures.
- 3. The method according to claim 1, comprising configuring said leaky wave antennas to transmit said RF signals at a desired angle from said surface of said support structures.
- 4. The method according to claim 1, wherein said support structures comprise at least one of: an integrated circuit, an integrated circuit package, and a printed circuit board.
- 5. The method according to claim 1, wherein said leaky wave antennas comprise microstrip waveguides.
- 6. The method according to claim 5, comprising configuring a cavity height of said leaky wave antennas by controlling spacing between conductive lines in said microstrip waveguides.
- 7. The method according to claim 1, wherein said leaky wave antennas comprise coplanar waveguides.
- 8. The method according to claim 7, comprising configuring a cavity height of said leaky wave antennas by controlling spacing between conductive lines in said coplanar waveguides.
- 9. The method according to claim 1, wherein said low-frequency signals comprise DC bias voltages.

10. The method according to claim 1, comprising communicating said RF signals from a single leaky wave antenna to a plurality of leaky wave antennas.

11. A system for enabling communication, the system comprising:

- one or more circuits for use in a wireless device comprising one or more leaky wave antennas integrated within and/or on a plurality of support structures, said support structures being coupled via flip-chip-bonding, wherein said one or more circuits are operable to:
  - communicate RF signals between said support structures via said one or more integrated leaky wave antennas; and
  - communicate low-frequency signals via contacts defined via said flip-chip bonding.

12. The system according to claim 11, wherein said one or more circuits are operable to communicate said RF signals between said support structures perpendicular to a surface of said support structures.

13. The system according to claim 11, wherein said one or more circuits are operable to configure said leaky wave antennas to transmit said RF signals at a desired angle from said surface of said support structures.

14. The system according to claim 11, wherein said support structures comprise at least one of: an integrated circuit, an integrated circuit package, and a printed circuit board.

15. The system according to claim 11, wherein said leaky wave antennas comprise microstrip waveguides.

16. The system according to claim 15, wherein said one or more circuits are operable to configure a cavity height of said leaky wave antennas by controlling spacing between conductive lines in said microstrip waveguides.

17. The system according to claim 11, wherein said leaky wave antennas comprise coplanar waveguides.

18. The system according to claim 17, wherein said one or more circuits are operable to configure a cavity height of said leaky wave antennas by controlling spacing between conductive lines in said coplanar waveguides.

19. The system according to claim 11, wherein said low-frequency signals comprise DC bias voltages.

20. The system according to claim 11, wherein said one or more circuits are operable to communicate said RF signals from a single leaky wave antenna to a plurality of leaky wave antennas.

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